materials

MDPI

Supplementary Materials

CuSCN as the Back Contact for Efficient ZMO/CdTe Solar Cells

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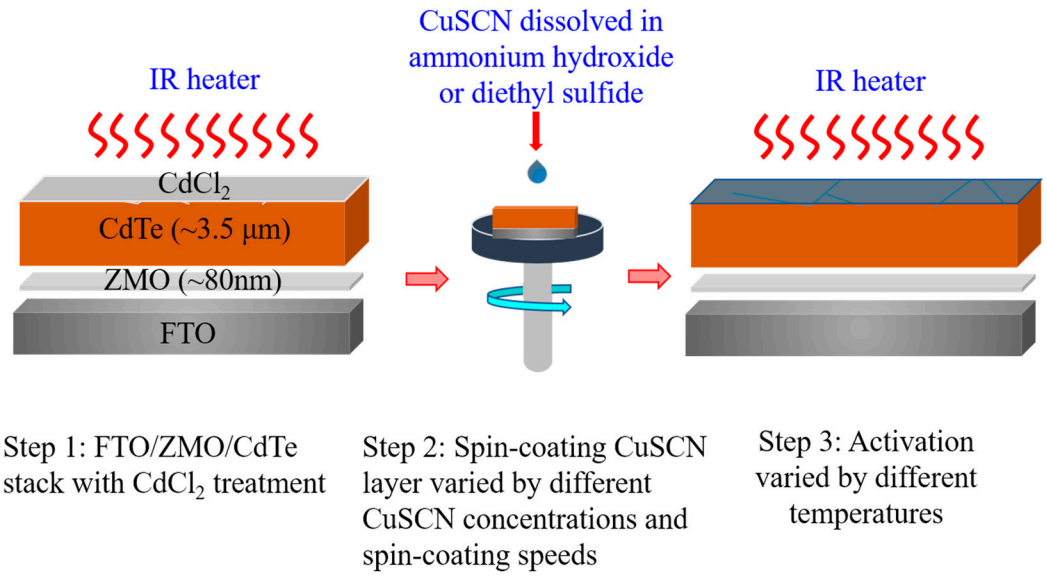

Figure S1. Schematic illustration of technological steps and investigation design in this work.

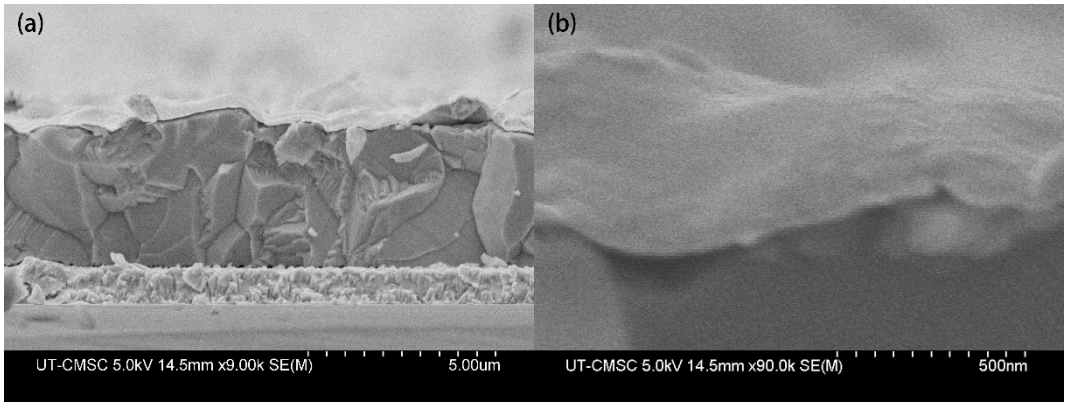

Figure S2. Cross-sectional SEM images of complete devices with CuSCN as back contact in (a) low and (b) high magnification.

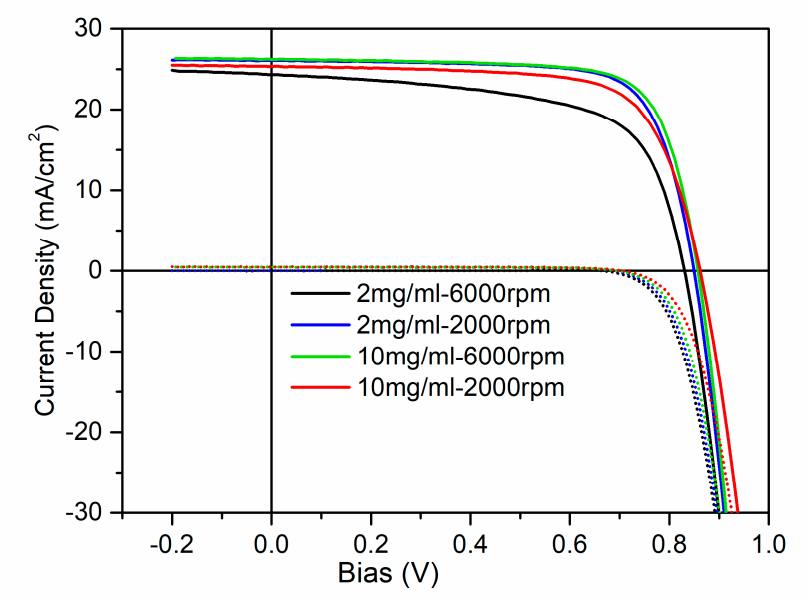

Figure S3. J-V curves the best cells in devices with different CuSCN thickness.

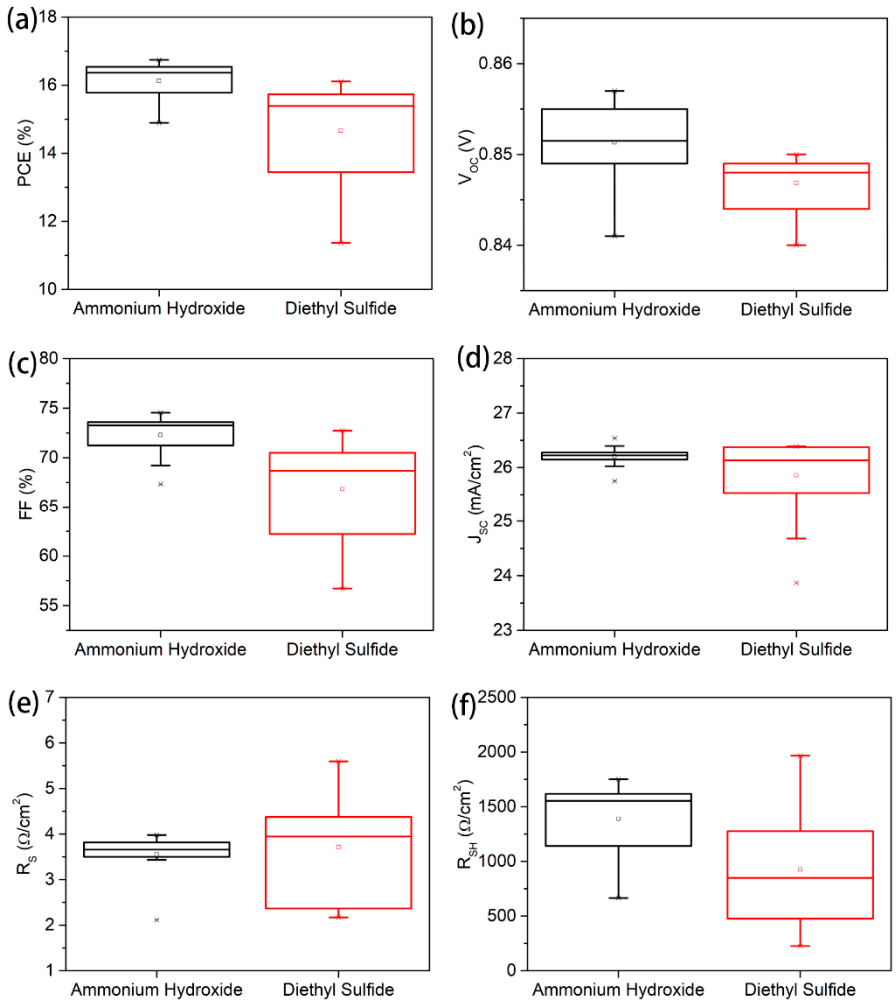

Figure S4. Statistical results for MZO/CdTe solar cell performances of (**a**) PCE, (**b**) V_{OC}, (c) FF, (d) J_{SC}, (e) series resistance (R_S), and (f) shunt resistance (R_{SH}) with different CuSCN solutions.